# Universality Classes of Metal-Insulator Transitions in Strongly

Correlated Electron System s and M echanism of

H igh-Tem perature Superconductivity

M asatoshi Im ada

Institute for Solid State Physics, University of Tokyo,

5–1–5, Kashiwanoha, Kashiwa, Chiba 277–8581

# Abstract

W e study three regim es of the M ott transitions characterized by classical, m arginally quantum and quantum. In the classical regime, the quantum degeneracy temperature is lower than the critical tem perature of the M ott transition, T<sub>c</sub>, below which the rst-order transition occurs. The quantum regime describes the  $T_c = 0$  boundary of the continuous transition. The marginal quantum region appears sandwiched by these two regimes. The classical transition is described by the Ising universality class. However, the G inzburg-Landau-W ilson scheme breaks down when the quantum e ects dom inate. The marginal quantum critical region is categorized to a new universality class, where the order parameter exponent , the susceptibility exponent and the eld are given by = d=2; = 2 d=2 and = 4=d, respectively, with d being the spatial exponent dim ensionality. It is shown that the transition is always at the upper critical dim ension irrespective of the spatial dimensions. Therefore, the mean-eld exponents and the hyperscaling description become both valid at any dimension. The obtained universality classes agree with the recent experimental results on the M ott criticality in organic conductors such as  $-(ET)_2 C u N (CN)_2 C land$ transition m etal compounds such as  $V_2O_3$ . The marginal quantum criticality is characterized by the critically enhanced electron-density uctuations at small wavenum ber. The characteristic energy scale of the density uctuation extends to the order of the M ott gap in contrast to the spin and orbital uctuation scales and causes various unusual properties. The mode coupling theory shows that the marginal quantum criticality further generates non-Ferm i-liquid properties in the m etallic side. The e ects of the long-range C oulom b force in the lling-control M ott transition are also discussed. A mechanism of high tem perature superconductivity emerges from the density uctuations at sm all wavenum ber inherent in the marginal quantum criticality of the M ott transition. The mode coupling theory combined with the Eliashberg equation predicts the superconductivity of the  $d_{x^2 \ y^2}$  sym m etry with the transition tem perature of the correct order of m agnitude for the realistic parameters for the cuprate superconductors. Experimental results on the electron differentiations established in the angle-resolved photoem ission experiments are favorably compared with the present prediction. The tendency for the spatial inhom ogeneity is a natural consequence of this criticality.

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## I. IN TRODUCTION

M ott transition belongs to one of the metal-insulator transitions ubiquitous in various com pounds<sup>1</sup>. Physical properties of M ott transition and its nature are a long-standing subject of research with many controversial issues. The problem has rst been postulated in 1937 by Peierls and Mott<sup>2</sup>. A lthough the band theory of metals and insulators established soon after the foundation of quantum mechanics is quite successful, it was pointed out by de Boer and Verway<sup>3</sup> that insulating behaviors of many transition metal compounds as N iO cannot be explained by a simple band picture, because the bands are partially lled. Peierls pointed out a crucial role of electron correlations as the mechanism of the insulating behavior. M ott developed this idea and introduced a concept which we now adays call the M ott insulator<sup>4,5</sup>. Since then, it has been recognized for a long time that the M ott insulator stabilized by the electron-electron Coulomb interaction and metallic states near it provide us with fuitful physics with various novel concepts. This has become very popular after the discovery of the high-T<sub>c</sub> cuprate superconductors, which was indeed discovered in doped M ott insulators<sup>6</sup>. How ever, relationship of this fruitful outcom e to the nature of the M ott transition itself has not been fully clari ed.

The M ott transition can be realized basically by two routes: B andwidth-control and lling-control. In the stroute, the bandwidth is controlled relative to the am plitude of the local electron-electron interaction by keeping the electron density xed at a commensurate value (namely, the electron density per unit cell is kept at an integer value). This route m ay be experimentally realized by applying pressure or by substituting elements with a dient ionic radius and the same valence. In this route, the overlap of the wavefunctions between neighboring electronic atom is orbitals forming conduction electron bands is controlled. In the second route, electron lling is changed from the M ott insulator. This is typically realized by substituting with elements, which have a dient valence from the substituted elements in the reservoir structure of the M ott insulator.

O riginally, M ott has considered only the stroute, the bandwidth-control transition. In this category, there exist several typical M ott transitions including those observed in  $V_2O_3$ , RN iO\_3 and -ET type organic compounds, where R represents a rare earth element. M any of them show stored transitions between the M ott insulator and m etals at low temperatures<sup>1</sup>. In m any cases, som e m agnetic and/or orbital order exist at low temperature

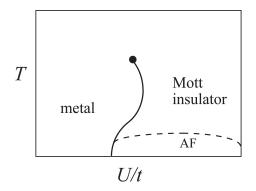


FIG.1: Schem atic and typical phase diagram of m etal and M ott insulator in the parameter space of tem perature T and the interaction strength scaled by the transfer, U=t. The solid curve shows the rst-order M ott transition with the critical end point illustrated by the solid circle. In m any cases, the antiferrom agnetic (AF) phase appears at low tem peratures as is illustrated by the broken phase boundary line.

of the M ott insulator phase. A blough som etim es concurrent magnetic transitions occur with the M ott transition at low temperatures, in the typical phase diagram illustrated in Fig. 1, the nst-order M ott transitions occur even at high temperatures, where the magnetic and orbital orders are not involved. This typical phase diagram clearly indicates that the M ott transition is inherently independent of the magnetic and orbital-ordering transitions. The statement that the mechanism of the M ott transition is primarily independent of the symmetry breaking of spins or orbitals is also corroborated by the existence of a quantum spin liquid phase in the M ott transition between a quantum spin-liquid and a metal does not accompany magnetic transitions. In fact, as we see in this paper, the M ott transition is not driven by the spin or orbital degrees of freedom but by the density degrees of freedom.

M ott argued that the long-range part of the C oulom b interaction is necessary to reproduce the rst-order transition<sup>12</sup>. The argument by M ott was the following: W e can identify the M ott insulating phase as that where the two electrons sitting on the same atom ic orbitals (we call it a doublon) and an empty site (we call it a holon) m ake a bound state. M etals are characterized by the phase where the bound state disappears. In terms of the binding of the doublon and holon, the binding energy is controlled by the screening of the attractive C oulom b interaction between the doublon and holon. Since the screening relies on other doublons and holons moving in between, the screening becomes rapidly poor with decreasing density of free doublons and holons. Then at some threshold concentration of free doublons and holons, the screening becomes too weak to keep a doublon and a holon free and as a consequence of this feedback, they suddenly form a bound state, which leads to a rst-order transition to a M ott insulating state. A nother argument for the origin of the rst-order transition emphasizes couplings to lattice distortion. When the metal is stabilized, the lattice constant diminishes further to gain the kinetic energy of electrons, which in general strongly favors the rst-order transition through the electron-lattice coupling.

However, recent detailed num erical studies on the Hubbard model on the square lattice overturned these speculations<sup>7,8,13</sup>: A lthough the long-range C oulom b force and the coupling to the lattice m ay have some roles in the realistic M ott transition, even the Hubbard model with only the local onsite interaction without any coupling to lattice distortions is enough to reproduce the rst-order M ott transition. The N-site Hubbard model is de ned as

$$H = H_t + H_{Ui} M N$$
(1)

$$H_{t} = \begin{array}{c} X \\ t_{ij} (c_{i}^{y} c_{j} + h c) \end{array}$$
(2)

and

$$H_{Ui} = U(n_{i''} - \frac{1}{2})(n_{i\#} - \frac{1}{2}):$$
 (3)

 $_i$   $n_i = N$  and  $n_i = c_i^y c_i$  with the creation (annihilation) operator  $c_i^y$  (c\_i ) Here, M of an electron at the site i with the spin . The chemical potential is and U is the onsite Coulomb repulsion. The phase diagram of the Hubbard model at zero tem perature T = 0 on the square lattice with the nearest-neighbor and next-nearest-neighbor transfers t and  $t^0$ , respectively, studied by the path-integral renorm alization group m ethod<sup>14,15</sup> is shown in the plane of U=t and the chemical potential at zero tem perature in Fig.  $2^{13}$ . lling-control transition occurs across the edge of the boundary in Fig. 2, while the The bandwidth-control transition is realized through the corner of the phase boundary at the bottom . The st-order transition through the bandwidth-control route is indicated by the  $m_{i''}n_{i\#}i = \int_{i}^{P} n_{i''}n_{i\#} = N$  as in Fig. 3 for the jump of the averaged doublon density D case of the anisotropic triangular lattice<sup>7</sup>. When the storder transition takes place at zero tem perature, its jump decreases with raising tem peratures and closes at the critical endpoint. In fact, the Hubbard model on this anisotropic triangular lattice is a relevant

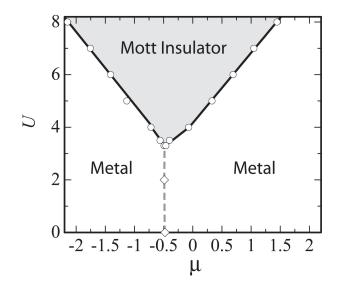


FIG.2: Phase diagram of M ott insulator (shaded area) and m etal for two-dimensional H ubbard m odel on a square lattice with the nearest-neighbor transfert and the second-neighbor transfer  $t^0$  in the plane of the local interaction U and the chem ical potential . The energy unit is t = 1 and  $t^0$  is taken at 0.2. The bandwidth-control route is realized across the bottom corner of the M ott phase boundary along the gray dashed line, whereas the ling-control transition occurs across the solid lines.

e ective model for the -ET type organic compound and the rst-order M ott transition with the nite-tem perature critical end point was observed experimentally  $^{16,17,18}$ .

A nother remarkable feature in Fig. 3 is that the jump in D decreases with increasing the next nearest neighbor transfer t<sup>0</sup>. This means that the so-called frustration e ects reduce the rst-order jump and drives to more continuous type transitions. In fact, recent experimental studies on pyrochlore compounds<sup>19</sup> appear to show a continuous M ott transition by the bandwidth control with a signature of the Anderson localization in the vicinity of the boundary. We note that the pyrochlore lattice has the fully frustrated structure, where the antiferrom agnetic order is severely suppressed. In addition, recent studies on -(ET)<sub>2</sub>Cu<sub>2</sub> (CN)<sub>3</sub> suggest that the critical temperature of the M ott transition becomes lower for the more frustrated structure, namely for compounds with larger e ective t in the corresponding theoretical model.<sup>20</sup> All of these consistently suggest that the order of the M ott transition may be system atically controlled from the rst order to continuous.

W hen the lling is controlled, the rst-order transition appears as the phase separation.

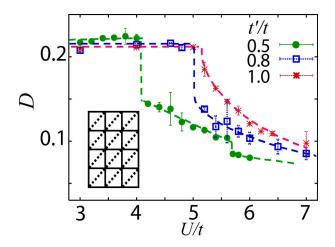


FIG. 3: Double occupancy D at T = 0 as a function of U=t for three choices of parameters,  $t^0=t=0.5;0.8$ , and 1.0 for the anisotropic triangular lattice structure depicted in the inset with the nearest neighbor transfer t (solid bond) and the next-nearest-neighbor transfer  $t^0$  (broken bond). Jum ps of D at U=t = 4:1;5:0 and 5.2 for  $t^0=t=0.5;0:8$  and 1.0, respectively show the rst-order M ott transitions. Curves are guide for the eyes

Experimentally, the existence of the phase separation or the electronic inhomogeneity is a controversial issue as we discuss later. From theoretical side, numerical studies on the Hubbard model show the marginal result, where the phase separation does not occur while the charge susceptibility shows a critical divergence at the M ott transition.<sup>21,22,23</sup> In the term inology in this paper, we use the charge susceptibility and the density susceptibility as the same quantity dhM i=d for the electrons with charge.

Since the theoretical and experimental results suggest the controllability of the order of the M ott transition and its critical temperature, it is desired to understand the whole feature of the M ott transition from the universality classes of the nite-temperature critical point to the zero-temperature critical phenomena on the same grounds. We will show in this paper that three regimes of the M ott transition exist. One is the classical transition at a high temperature, which is described by the Ising universality class of the critical point accompanied by the rst-order transition below the critical temperature. The second is the quantum transition, where the transition appears only at zero temperature, and the density susceptibility remains nite for the spatial dimension d 2. The third regime is the marginally quantum one, which emerges at the crossing point of the classical and

quantum transitions. The marginally quantum regime is characterized by the diverging density susceptibility at small wavenumber for d 2 at low temperatures. In the second and third regimes, the conventional scheme of the G inzburg-Landau-W ilson theory does not apply.

The new universality class at the marginally quantum transition has a deep consequence on the induced non-Ferm i-liquid behavior in the metallic side, electron dimension in the momentum space and the sensitivity toward electronic inhomogeneity. One of the most remarkable consequences is the superconductivity emerging from this marginal quantum M ott criticality. We show that the high temperature superconductivity of the  $d_{x^2 y^2}$  symmetry is obtained under the realistic choice of the parameter values for the cuprate superconductors, where the density (charge) uctuations at small wavenum ber play the crucial role for the Cooperpairing. The energy scale of the uctuation is characterized by the M ott gap, which can be by far larger than the energy scale of magnetic and orbital uctuations for the llingcontrol transition. This solves many puzzling experimental results in strongly correlated electron system s particularly in transition metal compounds.

A part of the discussions in this article is already given<sup>24,25</sup>. We summarize the previous results and further extend the discussion on the quantum M ott criticality and its consequences in greater detail. In particular, detailed analyses on the breakdown of the G inzburg-Landau-W ilson scheme for the quantum M ott transition are presented together with the scaling analysis. The validity of the mean- eld exponents and the compatibility with the hyperscaling description are discussed in detail. Two-dimensional systems are especially analyzed and are compared with the experimental results for the organic compounds and the cuprate superconductors. Basic nite temperature elects are also obtained and discussed in connection with the experimental results. An important issue for the llingcontrol transition is the elects of the long-range C oulom b interaction. We discuss how the present results are modiled in the presence of the long-range interaction and also discuss the experimental relevance. The non-Fermi-Hiquid properties and the anisotropic C ooper pairing originating from the nonperturbative enhancement of the density susceptibility at a sm all wavenumber is an important subject we study in this article in detail.

In Sec. II, we sum marize the conventional G inzburg-Landau-W ilson scheme of the M ott transition. In Sec. III, the nature of the quantum M ott transition is exam ined with emphasis on the breakdown of the G inzburg-Landau-W ilson scheme. Section IV is devoted to the

resultant non-Ferm i-liquid behavior expected in the metallic side of the critical region of the M ott transition. In Sec. V we discuss the mechanism of high-tem perature superconductivity arising from the marginal quantum M ott criticality. Section VI concludes and summarizes the paper.

# II. CONVENTIONALGINZBURG-LANDAU-WILSON SCHEME

Recently, the critical endpoint of the st-order transition line of the M ott transition in F ig. 1 has been a subject of intensive studies. In case of  $V_2O_3$ , from the detailed study of the conductance, it has been suggested that the criticality of the transition follows the Ising-type universality class<sup>26</sup>. In an organic conductor of -ET salt, the diverging electronic compressibility at the critical end point has been probed by the ultrasound velocity<sup>16</sup>.

In prior to these experimental studies, several theoretical studies have focused on the nature of the transition. The M ott transition by itself does not change any symmetry. Therefore, from theoretical point of view, it has an analogy with the text-book gas-liquid transition, which is known to be equivalent to the ferror agnetic transition in the Ising m odel under magnetic elds. The rst-order metal-insulator transition corresponds to the Ising transition between spin-up and down phases taking place with switching the direction ofm agnetic elds below the critical tem perature. In fact, C astellan<sup>27</sup> has discussed the Ising nature of the rst-order M ott transition by extending the B lum e-Em ery-G ri the dynam ical m ean- eld theory by K otliar et al<sup>29,30</sup>, where the low-energy part of the single-particle G reen's function appears to follow G inzburg-Landau scheme in accordance with the m ean-eld theory of the Ising m odel.

In the G inzburg-Landau-W ilson scheme for the Ising-type transition, the free energy may be expanded by the spatially dependent scalar order parameter X (r) integrated over space coordinate r as  $\frac{7}{2}$ 

$$F = dr \left[\frac{1}{2}a_0 (T - T_c)X (r)^2 + \frac{1}{4}bX (r)^4 - X (r)\right]$$
(4)

near the critical tem perature  $T_c$  with  $a_0$  and b being positive constants. In the Ising model, X is indeed the order parameter, namely, the magnetization m. In the mapping to the gasliquid transition, X is interpreted as the density of particles, n, measured from the critical density. At the critical temperature  $T_c$  of the gas-liquid transition, the uniform density susceptibility  $_n = [d^2F = dn^2]^1$  diverges.

W hen it is further extended to the mapping to the M ott transition, for the lling-control transition, X is identiced as the electron doping concentration X measured from the critical density at the critical point of the M ott transition<sup>24</sup>. This is a natural consequence, because, in the lling-control transition, the control parameter is the chemical potential, which is conjugate to the carrier density.

W hen the bandwidth is controlled, the control parameter is U=t in the Hubbard model and the conjugate quantity to U is the doulon density D. Therefore, the order parameter X in this case is the doublon density D, which indeed jumps at the rst-order transition as in Fig. 3. We note that in this case the holon density should be the same as the doublon density, because the holon and doublon densities must be the same to keep the density for the route of the bandwidth-control transition.

To describe the both types of the transitions, we take the natural order parameter as , where = X for the lling-control transition and = D for the bandwidth-control transition. Namely, we take

$$F = dr \left[\frac{1}{2}a_0 (T - T_c) (r)^2 + \frac{1}{4}b (r)^4 (r)\right]:$$
 (5)

Here, is U for the bandwidth-control transition whereas is the chemical potential conjugate to the doping concentration X for the lling-control transition. The Ising universality is resulted from this G inzburg-Landau-W ilson functional<sup>31</sup>. When the Ising universality is correct, we obtain the critical susceptibility exponent de ned by  $_{\rm c}$  [ $^{2}F=^{0}$   $^{2}$ ]<sup>1</sup> / (T T<sub>c</sub>) with = 7=4 for two-dimensional system s, d = 2 and 124 for d = 3. The order parameter exponent de ned below T<sub>c</sub> as h i / jT T<sub>c</sub>j obtained from  $^{0}F=^{0}e=0$  at = 0 satisfies estimates = 1=8 and 0:325 for d = 2 and 3, respectively. The exponent with varying de ned as h i /  $^{1e}$  at T = T<sub>c</sub> is given by = 15 and 4.8 for d = 2 and 3, respectively. These exponents for d = 3 were indeed claimed to be observed at the critical point of the bandwidth-control M ott transition for V<sub>2</sub>O<sub>3</sub><sup>26</sup>.

In the Ising-transition picture<sup>31</sup>, the transition is characterized by these simple exponents with the hyperscaling assumption being satis ed below the upper critical dimension  $d_{i} = 4$ . The system has a single length scale which diverges at  $T = T_{c}$ . In the present context, expresses the density correlation length or doublon density correlation length.

# A. General remark on quantum e ect

A nontrivial question arises when the critical tem perature of the M ott transition,  $T_c$  can be lowered. W ith lowering of  $T_c$ , how do the quantum e ects emerge? If  $T_c$  becomes zero, then one m ight naively expect that conventional quantum critical phenomena would appear. A naive expectation would be that the transition m ight be described by the Ising universality class in d + 1 dimensions, where the additional one dimensionemerges from the dimension in the imaginary time in the path integral form alism. It turns out later that this is not the case. In any case, the criteria for the existence of the non-negligible quantum e ect should be determined from the existence of the Fermi degeneracy of the electrons. W hen the Fermi i degeneracy temperature becomes comparable or higher than  $T_c$ , the M ott transition has to be treated fully quantum mechanically.

O nem ay argue that even when the bare Ferm item perature is high, the elective Ferm i tem perature would be suppressed near the M ott critical point, because, at the continuous transition point to the insulator, the Ferm idegeneracy tem perature should be zero. However, the Ferm idegeneracy m ay still coexist with the critical luctuation in the m etallic side near  $T_c$ . In fact, even when  $T_c$  is zero, the Ferm idegeneracy always appears at tem peratures su ciently close to zero, if the parameter in nitesim ally deviates from the critical point. Then the quantum elect should become relevant when one approaches the transition point by keeping the tem perature su ciently low.

In the quantum region, we have to consider quantum dynamics. This can be done by considering the path-integral form alism, where the in aginary time direction must be additionally considered in addition to the real spatial dimension. The time scale !<sup>1</sup> diverges as !<sup>1</sup> / <sup>z</sup> in addition to the divergence of the spatial correlation length . The quantum dynamics is characterized by the dynam ical exponent z. We note here that the M ott transition can be characterized by two di erent dynam ical exponents in principle. This is because at the M ott transition, the single-particle spectra given by the single-particle G reen's function and the two-particle correlations represented by the density (charge) correlation functions both have singular behaviors with diverging time scale, while these two may in principle follow di erent scalings. Therefore we can de ne two dynam ical exponents z and z for

single-particle and two-particle spectra, respectively. We will show below that these two coincide each other.

Here, we discuss how the quantum e ect alters the transition by assuming the region where  $T_c$  is low or even zero. When  $T_c$  becomes low, the G inzburg-Landau expansion tells that the charge uctuation becomes diverging accompanied by the quantum degeneracy, which becomes beyond the scope of the form (5). One might expect that the quantum region could be described by the Ising universality in d + z dimensions. We will show that this does not apply and the quantum e ect is more profound.

### B. W hat is di erent from the conventional quantum critical phenom ena?

In contrast to phase transitions with sin ple spontaneous sym m etry breakings, the transitions from m etals to the band insulators and the M ott insulators have no spontaneous sym m etry breaking by them selves. Therefore as in the gas-liquid transition, the m etals and insulators have no clear distinction at nonzero temperatures, if the st-order transition would be absent. However, at zero temperature, insulators are always clearly distinguished from m etals by the vanishing conductivity. A m ong various types of insulators, band insulators and M ott insulators both have clear distinction from m etals by vanishing D nude weight and vanishing charge susceptibility (compressibility) at zero temperature<sup>1,34</sup>. The D nude weight is the sti ness to the twist of the phase of the wavefunction in the spatial direction, while the charge susceptibility is the sti ness to the twist in the temporal direction in the path-integral form alism <sup>1,32,33</sup>. B oth of the two quantities have nonzero values only in m etals. Therefore, m etals under the perfectly periodic potential of ions are regarded as a state where sym m etry of the phase of the spatially-extended electron wavefunction is broken. Then, at zero tem perature, insulators cannot be adiabatically continued to a m etal. Two phases have to be clearly separated by a phase boundary.

From these facts, we notice that the M ott transition at zero temperature m ay have a quite di erent universality class. In fact, if one could lower  $T_c$  in Eq. (5) by controlling some m icroscopic parameter, one m ay also expect that it could pass through zero and even to a negative temperature. This implies that the transition would become quantum critical and then the M ott transition would disappear as in the conventional scenario of the emergence of quantum critical phenomena as schematically illustrated in Fig. 4 (a). However, we have

seen above that this cannot happen because of the clear distinction between m etals and insulators at T = 0. This by itself indicates that the G inzburg-Landau-W ilson scheme has to break down when  $T_c$  becomes zero. When  $T_c$  is lowered to zero, and if one tries to drive the control parameter further to lower  $T_c$ , it in reality keeps  $T_c$  at zero, namely the quantum transition at T = 0 continues as we see in Fig. 4 (b). We call this continuation line, the  $T_c = 0$  boundary. When  $T_c$  becomes just zero from nonzero values, we call this point the marginal quantum critical point, which is indicated by the solid circle in Fig. 4 (b).

We have discussed already that the rst-order transitions with the critical end point are indeed found in experiments. We have also discussed and will discuss later that the metal-insulator transition through the  $T_c = 0$  boundary appears to exist. Then the marginal quantum critical region is the crossing point of these two regions. We will clarify that m any strongly correlated systems including the high- $T_c$  cuprates m ay be located in this marginal quantum critical region. Numerical results of the lling-control transition in the two-dimensional H ubbard model indeed suggest a continuous transition at zero temperature with the diverging charge susceptibility (density susceptibility)<sup>21,22,23</sup>, which is consistent with what is expected in the marginal quantum critical region. Therefore, this quantum criticality is certainly a realistic possibility. From experimental point of view, the quantum parameter g m ay be controlled by the lattice structure, particularly, by the geometrical fustration as already discussed in xI. The control of the fustration parameter w as actually achieved by the choice of anions in -type ET compounds while uniaxial pressure m ay also be used to control the fustration e ects in general.

#### C. Single-particle quantum dynam ics

The m etallic phase except for one-dimensional systems has the adiabatic continuity with the Ferm i liquid. Therefore, low-energy part of the free energy can be described by the ferm ionic operators of renormalized single particles, where the higher-order terms are renormalized to the single-particle coe cient. In the insulating side as well, single-particle G reen's function G describes the charge dynamics and may be given from a quasiparticle description with a gap  $_{c}(q)$  as

$$G(q;k;!_n)^{\perp} = i!_n + E(q;k)$$
; (6)

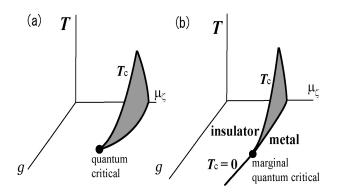


FIG. 4: Schem atic phase diagram of conventional quantum critical phenom ena (a) and the M ott transition (b) in the parameter space of the control parameter conjugate to the order parameter, the parameter g to control the quantum uctuation and tem perature T. In (b), the  $T_c = 0$  boundary continues as a line beyond the marginal quantum critical point. The shaded areas are the rst-order phase boundaries.

where the M atsubara frequency is  $!_n$ , and E (q;k) =  $p_{-c}(q)^2 + (q;k)^2$  with the bare dispersion ". In this expression, k is the momentum coordinate perpendicular to the bous of (q;k) = 0 and q denotes that parallel to (q;k) = 0. Here E (q;k) is assumed to satisfy E (q;k) 0( 0) in the electron-doped (hole-doped) region (, namely for the pole of the upper (lower) Hubbard branch ). The in aginary part of the self-energy Im and the renormalization factor Z is not considered here, because the singularities of the M ott transition are our main interest in this article while we assume that the singularities are not altered by Im and Z<sup>35</sup>.

Now we take the hole picture for the hole doping side so that E always takes E 0 both in electron and hole doped regions. Then, aside from the rigorous validity of the details of the above form for E, around the M ott gap edge, one can assume that the dispersion is expanded in term s of k as

$$E (q;k) = a(q)k^{2} + b(q)k^{4} + \dots$$
(7)

We have shifted the chem ical potential to cancel the gap  $_{c}$ . Here, the gap edge is not necessarily isolated points in the momentum space, but may be a line or a surface, which may evolve to the Ferm isurface in the Ferm iliquid. The k-linear term does not exist because we have assumed that k = 0 is the gap edge: The k-linear term violates the requirement

E 0 for small negative k. The cubic term should also be vanishing in the region of our interest because it becomes relevant only when a becomes su ciently small, while then the cubic term also violates the initial assumption of E (q;k) 0 for negative k. The analyticity of the dispersion at small k is our assumption. This is actually plausible when the transfer energy for the distant pair of W annier orbitals well converges to zero with increasing distance in the Hubbard-type m odels.

The coe cients a and b are obtained as renorm alized values after elim inating the higher order terms of the quasiparticle operator. In the metallic side, the rigid band picture is not justified. However, it is still legitimate to consider the quasiparticle dispersion around the Ferm i level and the coe cients a and b as elective quasiparticle coe cients obtained in the evolution process of the metallic phase. This means that a and b may depend on the distance from the M ott transition point, whereas they still behave continuously. It should be noted that the variations of a and b can again be renorm alized, which leads to independent a and b near the transition point.

If the gap edge is given by isolated points and the coe cients a(q) at these gap edges approach nonzero positive constants on the verge of the transition, the dynam ical exponent z characterized by the single-particle dispersion is given by z = 2 as in the generic transition to the band insulator<sup>36</sup> with a nite e ective mass of quasiparticles. We see below that this does not hold any more at the marginal quantum critical point.

From this quasiparticle description, the transition between metals and M ott insulators are described by the change in the quasiparticle dispersions. One of our central statements in this paper is that the criticality of the transition has one to one correspondence with the singularity of the quasiparticle dispersions. When the coellicient a stays positive through the transition at nite number of isolated points of gap edge, the free energy has a similar singularity with the transition between the band insulator and metals, which is the continuous transition at zero temperature along the T = 0 boundary in Fig 4 (b). The inst-order transition may evolve only when a becomes zero. In the following, we clarify how the character of the transition and the single-particle dispersion are related each other.

#### D. Relation to Free Energy Form

Here we relate the quasiparticle dynam ics and the singularity of the free energy at the M ott transition in the quantum region. W hen we take the path integral form alism with the in aginary time , the singular part of the free energy density is form ally written by using the quasiparticle dispersion E as

$$F = (T = N) \ln Z$$
(8)

$$Z = D_{i}()D_{i}()e^{S=~};$$
 (9)

where the e ective ham iltonian H generating the single particle excitation E in Eq. (7) is rewritten by using the G rassmann variables  $_{i}$  and  $_{i}$  at the site i.

The above quasiparticle form leads to the e ective action at the chemical potential as

$$S = X_{(q;k;!_{n})(i!_{n} + E(q;k))(q;k;!_{n})}$$
(11)

with the M atsubara frequency  $!_n$ .

Let us not study the lling-control transition. A lthough the expansion (5) does not hold in the quantum region, the singular part of the free energy at zero tem perature still has an expansion with respect to the doping concentration X. From the M atsubara-frequency and wavenum ber dependent path integral form of the quantum dynamics leading from Eqs.(8) to (11), we obtain for the singular part of the free energy density at the transition,

$$F = X \qquad T \qquad dE D (E) \log (1 + e^{(E) - T})$$
(12)

with D (E) being the singular part of the density of states of quasiparticles. The Boltzm ann constant is taken to be unity for our tem perature scale. The particle density measured from the insulating phase is given by

$$X = \int_{0}^{Z_{1}} dE f(E) D(E)$$
(13)

with the Fermi distribution function  $f(E) = 1 = (e^{(E_{-})=T_{-}} + 1)$ .

We rst consider zero tem perature and the case where the dispersion E has m in in a at nite number of isolated points in the momentum space with the dispersion given by Eq.(7).

Then the particle density is given by

$$X = A_d k_F^d ; (14)$$

where  $A_d$  is a dimensionality-dependent constant and  $k_F$  is the Ferm i wavenum berm easured from the gap edge at the dispersion m in in a. Here we ignored the possible an isotropy of  $k_F$ because it does not alter the essential part of the results below for the scaling properties.

From the above relations, at T = 0, we have

$$F = X + A_{d} \left[ \frac{2a}{d+2} \left( \frac{X}{A_{d}} \right)^{\frac{2}{d}+1} + \frac{4b}{d+4} \left( \frac{X}{A_{d}} \right)^{\frac{4}{d}+1} + \right]:$$
(15)

W e note that we are considering only the singular part of the free energy at the transition.

W hen the dispersion proportional to a around these points  $q_1$  in Eq.(7) is present, the quasiparticle picture predicts that the total free energy measured from the insulator has the lowest order term at T = 0 as

$$F + X / aX^{(d+2)=d}$$
: (16)

From this free energy form, the charge susceptibility shows the scaling  $_{\rm c}$  ( $\ell^2 F = \ell X^2$ )<sup>1</sup> / X<sup>12=d</sup>, which is the same as the transition to the band insulator. Then the rst-order transition does not take place, because the charge susceptibility does not diverge for d 2. The metal insulator transition is well de ned only at zero temperature. This means that the transition occurs across the  $T_c = 0$  boundary illustrated in Fig. 4.

By starting from this continuous transition at zero tem perature, the rst-order transition can evolve in two fashions. One possibility is the case where a large Ferm i surface satisfying the Luttinger theorem appears in mediately upon doping. In this case, one has to take that Ferm i surface as the locus E(q;k) = 0 and one gets

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$$F + X / X^{3}$$
 (17)

by eliminating  $k_{\rm F}\,$  from

$$X / dk$$
(18)

and

$$F + X / k^2 dk;$$
 (19)

where we perform the integrations in the region around the locus E = 0 with the assum ption a > 0 everywhere. In this case, one gets the charge susceptibility  $_{c}$  ( $e^{2}F = e^{2}X^{2}$ )<sup>1</sup> /  $X^{-1}$ , which m eans that the transition occurs at the marginal quantum critical point, where  $T_c$  is still zero. This is because  $_c$  diverges only at X = 0 at zero temperature. To realize the phase separation (namely, the rst-order transition), we need a further additional degeneracy of the dispersion at the gap edge.

The second possibility is the marginal quantum critical point emerging with the vanishing a term at some isolated points  $q_0$  of the gap edge. In this case, we have the lowest order term

$$F + X / bX^{(d+z)=d}$$
; (20)

with z = 4, which yields

$$_{\rm c}$$
 / X <sup>1 z=d</sup> : (21)

The exponent z = 4 appears because we are left with the quartic term proportional to b when the quadratic term proportional to a vanishes.

# E. Electron di erentiation

Now it turns out that the two possible ways of realizing the nst-order transitions eventually become merged to a united picture, because even when we have the bours of E = 0with Eq.(17) being satistical a further attening of the dispersion at the gap edge with vanishing a is required to realize the nst-order transition. It is unlikely that such a attening emerges uniform by on the bours E = 0. Instead, it generically occurs from particular points of the bours because of the initial anisotropy of the Ferm i surface in the band structure and the anisotropic correlation elects as well. Now each, the point with the smallest amplitude of a becomes zero nst as a special point of the E = 0 surface. Then a quartic dispersion appears at this special point of the E = 0 surface when the system becomes marginal, which results in z = 4.

Therefore, the M ott criticality of the marginally quantum critical point is also characterized by an inevitable evolution of the electron di erentiation, if the large Ferm i surface is involved in the metallic side. The singular di erentiation generates a quartic dispersion at particular points of the Ferm i surface coexisting with dispersive generic part.

#### F. Comparisons with num erical and experim ental results

This large dynamical exponent z = 4 was suggested in several independent numerical calculations for the lling-control transition of the Hubbard and t-J models in two dimensions at  $T = 0^{-1/34}$ . These are the exponent estimated from the compressibility in the form  $(21)^{21,22,23,37}$ , the D rude weight D estimated from the form D / X  $^{1+(z-2)=d38,39}$ , single-particle dispersion<sup>40</sup> and the localization length / ( \_\_\_\_\_\_\_c)  $^{1=z}$  in the insulator side estimated from G reen's function Eq.(6), where is obtained from the Fourier-transform ed spatially-dependent G reen's function G (r; ! = 0) exp(r=)^{41}. These imply that the Hubbard and the t-J models are located close to this marginal quantum critical point.

A lthough the quasiparticle picture does not hold, it has num erically been shown that the dynam ical exponent indeed becom es z = 4 at the marginal quantum critical point in the one-dimensional H ubbard model with next-nearest-neighbor transfers<sup>42</sup>. This suggests that the form (20) is universally valid irrespective of the applicability of the quasiparticle picture.

It is insightful to compare experimental results obtained for the high- $T_c$  cuprates with the present picture of the electron dimension. In the high- $T_c$  cuprates, at dispersions are universally observed near (;0) and (0; ) points in the angle-resolved photoem ission experiments<sup>43,44</sup>. This atness is beyond the conventional expectation obtained from the van H ove singularity, while it is a natural consequence, if the M ott critical point at T =  $T_c$ is located at low temperatures. At and below  $T_c$ , vanishing quadratic dispersion, given by a = 0 should emerge in a region of the expected Ferm i surface.

The distance from the marginal quantum critical point in the phase diagram in Fig.4 m ay depend on details of materials and models. In addition, the actual q<sub>0</sub> positions responsible for the marginal quantum M ott criticality may also depend on materials and models. For example, the change in relative amplitude of t<sup>0</sup> to t in the Hubbard model (3) may change the location of q<sub>0</sub>. This may even change the nature of the transition from the route across the  $T_c = 0$  boundary to the route through the rst-order transition illustrated in Fig.4. This change may indeed occur from one high- $T_c$  compounds to another<sup>24,45</sup>. A ctually the singular points q<sub>0</sub> may deviate from (;0) and (0; ) points for larger t<sup>0</sup>. Width of the critical region may be in uenced by the amplitude of t<sup>1</sup> as well.

For the moment, de nite assignments are not possible, but we infer two possibilities for the cuprates. One is that the system is indeed close to the marginal quantum critical

point and the M ott criticality is controlled by the at dispersion. Even when the M ott criticality is controlled by these at points, the experimental observation of the at part of the dispersion at the Ferm i level m ay have some di culty because the strong damping is inevitably accompanied. The arc structure is observed in the angle-resolved photoem ission experiments for the underdoped cuprates, which literally means that the Ferm i surface around the at-dispersion region is missing. This implies that the experimental resolution might not allow the detection of the Ferm i surface around the at part, because of the strong damping, while this at part may govern the criticality.

The other possibility is that the part of the at dispersion is slightly away from the M ott gap edge. This is inferred from the fact that the at-dispersion level in the holedoped cuprates is slightly lower than the arc part around (=2; =2), which is the dispersion m inimum (in the hole picture) at the realM ott gap edge indicated by experiments<sup>44,46</sup> and by m odel calculations as well<sup>35</sup>. In this case, with the lowering doping concentration, the system

rst shows the marginal quantum critical behavior relecting the lat dispersion. However, with further approaching the real critical point, it crossovers from the marginal quantum criticality characterized by z = 4 to the ordinary class z = 2, which eventually lows to the criticality for the  $T_c = 0$  boundary. The real high- $T_c$  cuprates appears to have a variety between these two possibilities depending on the compounds. We will discuss consequences of the latter case further in Sec. IIIK.

A side from these details and uncertainties, the overall structure of very di erent evolutions of the Ferm i surface depending on the momenta is completely consistent with the picture that the transition metal compounds including the cuprates show electron di erentiation arising from the proximity of the marginal quantum M ott criticality. Electron di erentiation should become prominent when the system becomes closer to the marginal quantum critical point, while the electrons are more or less uniform along the  $T_c = 0$  boundary.

# G. Breakdown of Ginzburg-Landau-Wilson scheme

From the results in Secs. IIIC and IIID, the free energy near the marginal quantum critical point is generally expressed as

$$F = X + aX^{(d+2)=d} + bX^{(d+4)=d};$$
(22)

where a and b have absorbed num erical constants in Eq.(15) as well as e ects of the renormalization factor Z being less than unity, and the constants have properly been rescaled.

Even in the case of the bandwidth-control transition, when one can regard the closing of the gap by hole doping around a point  $q_{Dh}$  and simultaneous particle doping around  $q_{Dp}$  with the constraint of keeping the electron density n = 1, the above relation Eq.(22) m ay be replaced with D as

$$F = UD + aD^{(d+2)=d} + bD^{(d+4)=d};$$
(23)

because the \doublon" and \holon" concentrations are nothing but the above self-doping concentration of particles and holes.

Now instead of Eq.(5), the free energy at zero tem perature is expanded by and obtained after rescaling of the parameters as

$$F = + a^{(d+2)=d} + b^{(d+4)=d} + c^{(d+6)=d}$$
(24)

with the constraint 0. It should be noted that this expansion of the free energy in terms of is obtained from the path integral form with the spatial as well as in aginary time dependence explicitly taken into account. This form of the free energy clearly violates the G inzburg-Landau-W ilson scheme because the form of the free energy itself has d dependent nonanalytic expansion.

The metal-insulator transition across the  $T_c = 0$  boundary with a > 0 is driven by the term in Eq.(24). When is negative, the free-energy minimum exists at = 0, which corresponds to an insulator. Whereas the metallic phase is represented by the minimum at a nonzero positive , which is realized by a positive . The  $T_c = 0$  boundary is determined from = 0. The criticality of this  $T_c = 0$  boundary is given for the order parameter as

In the  $\mbox{mean-eld}$  approximation", is obtained from the spatially uniform derivative @F = @ = 0 as

$$= d=2:$$
 (26)

The susceptibility is given by

$$= \left[\frac{d^{2}F}{d^{2}}\right]^{1} \qquad \left[\frac{2(d+2)}{d^{2}}a^{2=d-1}\right]^{1};$$
 (27)

leading to the susceptibility exponent de ned by

in the metallic side < 0 as

$$= 1 \quad d=2:$$
 (29)

At = 0, we obtain another exponent from

with

in the m etallic side. These are all \m ean- eld exponents", although we will show these exponents are indeed correct. In the G inzburg-Landau m ean- eld theory, the critical exponents do not depend on the dim ensionality. However, this d-dependent form of the free energy leads to the d dependent exponents even in the m ean- eld treatm ent.

W hen a becomes zero, the critical point = 0 becomes marginal and the rst-order transition evolves if a becomes negative. This point with = a = 0 at T = 0 is nothing but the marginal quantum critical point. Namely, the marginal quantum critical point at T = 0 may be reached at a control parameter  $g = g_c$ , for  $a = a_0$  ( $g = g_c$ (T)),  $a_0 > 0$  and b > 0.

O nem ight argue that the marginal quantum critical point looks similar to the conventional tricritical point<sup>47</sup> because the continuous transition converts to the rst-order transition at T = 0 at this point. However, it is qualitatively dimensional competitions a priori exist.

Similarly to the transition across the  $T_c = 0$  boundary, the critical exponents of the marginal quantum critical point have d dependent form s even in the mean-eld treatment. The exponent de ned by the order parameter at g < g and = 0 as

is given by

$$= d=2:$$
 (33)

 $N ear g = g_c$ , is expressed as

$$= \left[\frac{d^{2}F}{d^{2}}\right]^{1} \qquad \left[\frac{2(d+2)}{d^{2}}a_{0}(g-g_{c})\right]^{2=d-1} + \frac{4(d+4)}{d^{2}}b^{4=d-1} + \frac{6(d+6)}{d^{2}}c^{6=d-1}\right]^{1} : \quad (34)$$

Then

holds in the metallic side  $g < g_c$ , yielding the m ean - eld'' exponent

$$= 2 \quad d=2:$$
 (36)

 $Atg = g_c$ ,

b<sup>1</sup> (37)

with

$$= 4 = d$$
 (38)

is obtained. We note that the divergence of the susceptibility is stronger at the marginal quantum critical point than along the  $T_c = 0$  boundary. It is also stronger for lower spatial dimensions. For example, is 1 and 1/2 in two and three dimensions, respectively, for the marginal quantum criticality. On the contrary, is not positive in two and three dimensions along the  $T_c = 0$  boundary.

Even though the G inzburg-Landau-W ilson scheme breaks down, the scaling relations = + and + 2 + = 2 are satis ed both for the  $_{c}T$ = 0 boundary and the m arginal quantum critical point. A long the  $T_{c}$  = 0 boundary we obtain = 1 d=2 while = d=2 for the m arginal quantum criticality. They are consistent with the hyperscaling law 2 = (d +  $z_{t}$ ) with = 1=2 and z = 4 for the m arginal quantum criticality and  $z_{t}$  = 2 along the  $T_{c}$  = 0 boundary. Here,  $z_{t}$  should be the dynam ical exponent of this M ott transition, namely the dynam ical exponent for the density or doublon density correlations, which turns out to coincide with the dynam ical exponent for the single particle excitations, z determ ined from the quasiparticle dispersion.

We can also con m that the hyperscaling relation is satis ed in the following way: The scaling relation and the exponents are derived from the scaling form of the free energy,

$$F(a; ) = \overset{dz_{t}}{f}(a^{y_{g}}; \overset{y}{f})$$
(39)

with a scaling function f and the correlation length

$$/ (g q_{\rm f})^{1=2} / {}^{1=d};$$
 (40)

which implies  $y_g = 2$ . Here the crossover exponent y = 4 (y = 2) is derived from the dynamical exponent of the density uctuations given by z = 4 ( $z_t = 2$ ) for the marginal

quantum criticality ( $T_c = 0$  boundary), respectively. The hyperscaling relation holds because this scaling form (39) is satisfied. In fact this scaling form is derived from the single length scale which diverges at the transition point. This correlation length is indeed proportional to the mean carrier distance / X<sup>1=d</sup> in the lling-control transition. This is obviously the single length scale which diverges at the transition. Satisfaction of the hyperscaling form (24) also clearly shows that this criticality is the consequence of the spatio-tem poral quantum dynamics of two-particle excitations in the path integral form, where d and  $z_t$ represent spatial and in aginary-time uctuations, respectively.

# H. Two-dim ensional case

In one and two dimensions, the powers of expansions in Eq.(24) stay at integers (for example, in 1D, (d+2)=d reduces to 3 and in 2D, (d+2)=d reduces to 2). In two dimensions, the free energy is reduced to

$$F = + a_0 (g g_c)^2 + b^3 + c^4:$$
(41)

This again does not belong to the conventional scheme of the G inzburg-Landau-W ilson form alism, because the odd order term (the cubic term here) is not allowed in the conventional Landau expansion from the constraint of the symmetry around the critical point. This has some resemblance to the breakdown of the G inzburg-Landau-W ilson scheme at the Lifshitz point of the structural transition although the physics contained here is quite dient. Here the asymmetry is allowed because the part of negative does not exist. This can be easily understood in the analogy to the trivial metal to the band-insulator transition, where the carrier density cannot be negative either. Even in the transition between metals and band insulators in the noninteracting systems, the free energy has a similar form to Eq.(24) and the G inzburg-Landau-W ilson scheme does not hold.

In the M ott transition in two dimensions, the susceptibility is given by

$$= \frac{d^2 F}{d^2} \int_{-\infty}^{1} \frac{1}{2a_0 (g - g_c) + 6b + 12c^2}; \qquad (42)$$

Then, = 1; = 1 and =  $2 \text{ hold}^{4,25}$ . Remarkably, this agrees with recent experimental results on a -ET compound,  $-(\text{ET})_2 \text{Cu} \mathbb{N}$  (CN)<sub>2</sub> ]C lby K agawa, M iyagawa and K anoda<sup>18,20</sup>. The exponents of the nite-tem perature critical point estimated by the conductance are

indeed consistent with these values for ; and within the experimental accuracy. We note that this compound has a structure of highly two-dimensional anisotropy. For the moment, it is not well claried how the crossover to the three dimensionality arising from weak three-dimensional coupling should appear experimentally. We will discuss below that these unusual exponents are also obtained practically even at nite temperatures, which is relevant in the realistic experimental condition of the nite-temperature Mott transition.

#### I. Validity of the mean-eld theory

Very close to the marginal quantum critical point, the present mean-eld exponent only marginally breaks down, because the G inzburg criterion<sup>31</sup> d +  $z_t$  (2 + )= with = 1=2 being the correlation length exponent indicates that the system is always at the upper critical dimension irrespective of the dimensionality, because the equality d +  $z_t$  = (2 + )= always holds. Here, = 1=2 is a direct consequence of  $y_q$  = 2. The uctuation beyond the mean-

eld theory becom es irrelevant above the upper critical dimension. A lthough logarithm ic corrections may exist, the mean-eld description is thus basically correct at any dimension in this case. This explains why the  $\mbox{mean-eld}$  exponents" are observed in the -ET compound. Below we restrict our analysis to the mean-eld study because the primary exponents are correct. A lthough the mean-eld exponents are correct, the hyperscaling also holds at any dimension. This peculiar compatibility is explained by the fact that the system is always at the upper critical dimension at any dimension. D etailed analysis of corrections based on the renorm alization group study will be reported elsew here. The sam e argument for the validity of the mean-eld exponents is applied for the T<sub>c</sub> = 0 boundary.

A lthough the diverging density uctuation is an inevitable consequence of the M ott critical point for the marginal quantum criticality and the classical Ising criticality, it is highly nontrivial e ect from the view point of the weak coupling picture. In fact, naive perturbation expansions result in suppressions of the density uctuations when the M ott transition is approached and the available perturbative treatment fails in reproducing this criticality. The one-loop calculation does not account for the M ott criticality, which in principle has to be explained in the real part of the self-energy to be calculated from the higher order loops, while it is so far an open issue to be derived in the future. In this sense, even the mean- eld theory is not a straightforward fram ework in contrast with most of the mean- eld theories as those in magnetic transitions.

#### J. Finite tem perature e ect

The parameter g also has temperature dependence, because the quasiparticle dispersion in general has a temperature dependence. As we have clarified above, g is determined from the quasiparticle dispersions. Therefore g  $g_c$  can be replaced by T  $T_c$ , where the critical temperature becomes nonzero. This is the dominant in ite-temperature e ect at low temperatures. However, we have quite independent origin of the inite-temperature e ects originating from the entropy term T in in addition to the above temperature dependence in the free energy F. This generates an essentially singular contribution for < 0, because the free energy has the extrem um at  $_0 / \exp[=T]$ . This is an exponentially small contribution at low temperatures for < 0. Therefore, it does not contribute to the present scaling behavior near T = 0 in the power of T. At high temperatures, how ever, without the Ferm i degeneracy, the expansion around the extrem um reproduces the regular G inzburg-Landau form

$$F_{T} = \frac{A_{0} (T - T_{c})^{2}}{2} + \frac{B^{4}}{4} \qquad ; \qquad (43)$$

when we rede ne as  $_0!$ 

When T is nonzero, strictly speaking, the Ising universality class may appear in the region extremely close to the critical point even at low temperatures. However, this real critical region becomes exponentially narrow with decreasing temperatures and the quantum criticality governs out of this region. This crossover of the criticality is due to the essentially singular contribution of the entropy term.

The results obtained for  $V_2O_3^{26}$  indicates that  $T_c$  is above 400 K and is high enough so that the Ising classical universality is well observed. On the other hand,  $T_c$  for - $ET_2Cu[N(CN)_2]Cl$  is below 40K and low enough<sup>18</sup>, so that the quantum region dom inates in the experimental results. All of these are consistent with what were observed. More quantitative analyses are left for future studies. K. E ects of long-range part of C ou lom b interaction for lling-control transitions

The role of the long-range part of the Coulomb interaction between electrons is sometimes controversial. In this subsection, we clarify how the long-range interaction modiles the conclusions obtained for the models only with the short-range interaction. Because the phase separation occurs for models with only the short-range force as the inst-order transition in the classical region, we restrict ourselves to the case of the Ising classical universality in this subsection, Sec.IIIK. Because of the long-range part and the resultant electrostatic condition, the real phase separation into two dilement electron densities is not allowed in the

lling-control M ott transition. Re ecting the electrostatic condition, the diverging charge susceptibility at strict zero wavenum ber is eventually suppressed for the lling control transitions. However, it still causes critical uctuations at nonzero and sm all wavenum bers.

The Poisson equations for the external test charge  $_{\rm ext}$  and the induced charge  $_{\rm ind}$  are given by

$$r^{2}_{ext} = -\frac{ext}{i};$$

$$r^{2}_{ind} = -\frac{ind}{i};$$
(44)

where  $_{ext}$  is the electrostatic potential generated by the external test charge, while the induced charge generates additional potential  $_{ind}$ . The dielectric constant is . When the external test charge  $_{ext}$  is at the origin with the unit charge, in metals, the Thomas-Ferm i screening occurs as  $_{ind} = __{tot}$  for weakly k-dependent term with the denition of the total electrostatic potential  $_{tot} = _{ext} + _{ind}$ . In fact, by the Thomas-Ferm iscreening, is estimated as  $= 2m \exp_F = ( \sim^2)$ , where m; e and  $q_F$  are the electron electron electron of the Ferm i wavenum ber, respectively. Here we have assumed isotropic sphere of the Ferm i surface for simplicity. Since the external test charge at the origin leads to a wavenum ber independent form  $_{ext}(q) = 1$  in the momentum representation, we obtain

$$_{tot} = \frac{1}{+ q_1^2}$$
(45)

and the resultant induced charge as

$$_{\text{ind}} = \frac{1}{1 + q_1^2}; \tag{46}$$

which indicates the Yukawa-type normal screening,  $_{ind}(r) = \exp\left[2^{p} - r\right] = r$  in the real space. When one considers the susceptibility as the linear response induced by the imposed

external charge as the perturbation, the susceptibility defined by  $_{ind} = _{ext}$  is now given by

$$= - + \hat{q}^{2} :$$
 (47)

W hereas, if the Coulomb potential is regarded as the perturbation, the linear response de ned by  $_{ind} = _{c ext}$  is given by

$$_{c} = \frac{\dot{q}}{+ \dot{q}}; \qquad (48)$$

which shows that the charge susceptibility is suppressed near q = 0 because of the long-range C oulom b force. W ith this screening, the free energy in the classical region is modiled to

F (r) = 
$$dr_{2}^{0} dr_{c}^{1}$$
 (r r<sup>0</sup>)X (r<sup>0</sup>)<sup>2</sup> +  $\frac{1}{4}$ bX (r)<sup>4</sup> e X; (49)

where the Fourier transform ed susceptibility is given by

$$_{c}^{1}(q) = _{CH}^{1}(q) + \frac{1}{q_{1}^{2}};$$
 (50)

$$_{CH}^{1}(q) = \frac{1}{-} + c()q^{2}$$
: (51)

Here,  $_{CH}$  is the charge susceptibility for the H ubbard m odelw ithout the long-range C oulom b part. The second term in the right hand side of Eq.(50) represents the long-range C oulom b interaction. The scaling of near the critical point is determined from the elective m ass m and is given as  $/ \frac{4 \text{ d}}{4 \text{ d}}$  and the function c() scales as c()  $/ \frac{2 \text{ d}}{2 \text{ d}}$ . The charge susceptibility is enhanced except for extrem ely small wavenum ber.

In the realistic condition, the minimum of Eq.(49) appears at  $q_{min} = 1 = (c)^{1-4}$ . In the cuprates, this is roughly estimated to be  $q_{min} = 0.1$ , since is the order of 10–100, and c = 10 as we see below. Namely, the charge susceptibility becomes strongly enhanced in the region of small wavenum bers, which are in the order of one tenth of the Brillouin-zone size, 2. Even around the marginal quantum M ott criticality, this induces a \softening" of the charge response with poor screening in the nm length scale, which causes strong dynamical uctuations of electron density at these small wavenum bers. This provides us with mechanisms of various unusual properties for metals near the M ott insulator. If F becomes negative at  $q_{min}$ , an instability toward the charge ordering occurs.

Even when T is below  $T_c$  in the Hubbard-type models, where only the short-range force is considered, the phase separation dynamics toward the q = 0 mode in reality freezes at a stage of a nite q constrained from the long-range repulsion for the lling-control transition. It should be noted that in the bandwidth-control transition, the divergence at q = 0 indeed occurs. This is because the electrostatic condition is not violated for the diverging doublon susceptibility.

We now realize that the larger dielectric constant induces the larger enhancement of the charge susceptibility as obtained by substituting  $q_{n in}$  into Eq. (50). A ctually, if good m etallic carriers independently exist in addition to the strongly correlated electrons which yields the doped M ott insulator, such good m etallic carriers e ciently screen the long-range C oulom b interaction of the correlated electrons. This allows more possibility for the part of the correlated electrons to approach the marginal quantum critical point. In fact, when the good m etallic carriers perfectly screen the motion of the correlated electrons, it corresponds to the limit ! 1 in the above argument and the diverging density susceptibility for the correlated part of electrons can indeed occur at q = 0, because the density uctuations are completely compensated by the good-metallic carriers except for the onsite interaction. This may occur in a two-band system, where one band has large bandwidth supplying good m etallic carriers, and the electrons on the other band are strongly correlated near the M ott insulating phase. Although it is not a simple two-band system, the situation in the holedoped cuprate superconductors is in a sense ideal from this view point, because upon the carrier doping, \good m etallic carrier" rst appears around the (=2; =2) region of the Ferm i surface, while the carriers near (;0) region with strong correlation e ects become doped in the presence of these itinerant carriers. Then the instability for the phase separation or the inhom openeity actually occurs as the inhom openeity of the  $\langle (; 0) \rangle$  carriers" compensated by the "(=2; =2) carriers". To realize this situation, it appears to be in portant to recognize that the cuprates are located close to the marginal quantum critical point, but strictly speaking located slightly in the side of the  $T_c = 0$  boundary.

Even when the charge ordering or the phase separation does not occur, the spatial inhom ogeneity is easily driven by in purity potential or lattice distortions, because of the underlying enhanced density susceptibility. This may be relevant as the mechanism of the structure observed by scanning tunnelm icroscopy (STM) in the cuprates and manganites<sup>48,49,50,51,52</sup>. The spatial inhom ogeneity in the long length scale (typically at 1 to 10 nm scale) observed experimentally cannot be explained by the naive Thomas-Ferm iscreening length  $_{\rm TF}$ , since nom inally  $_{\rm TF}$  is the order of 1=q<sub>F</sub> 0.3nm. The inhom ogeneous structure may also be enhanced by the experimental condition probed at the surface. The present results obtained

from the M ott criticality has a tight connection to the approach from dynamical stripe  $uc-tuations^{53,54}$ , while the importance of the underlying M ott criticality has not been recognized in the literature.

## IV. NON-FERM I-LIQUID PROPERTIES

## A. M ode coupling theory

Now we discuss the consequences of the enhanced density susceptibility near the marginal quantum critical point. W ithin the mean-eld theory, we assume the dom inant part of the susceptibility in the vicinity of a small and nonzero momentum Q and around the zero frequency as

$$(q;!) = \frac{1}{1 + D_{s} (K^{2} + (q Q)^{2} + ; )}$$
(52)

where  $D_s$  is the di usion constant of the density uctuations, K is the distance from the marginal quantum critical point, and is a constant. Near the critical point, they follow the critical scaling as 1 / d; K / 1 and  $D_s / 2$ , which reproduces the above scaling Eq.(35) with Eq.(40) at ! = 0. This again satis as the dynam ical exponent z = 4 because ! scales as  $D_s K^2 / 4$ , while the scaling of K reproduces = 1=2. Since it is at the upper critical dimension, this 0 mstein-Zemike-type form is justified. We note that the enhancement is much stronger for d = 2 than d = 3.

It should be noted that the characteristic energy scale of this charge uctuation is much larger than that of spin and orbital uctuations, because  $c()\hat{q}$  should typically have the energy scale of the M ott gap at the boundary of the B rillouin zone. This is clear because at the zone boundary, the density uctuation requires generation of the spatially alternating doublons and holons. Then D<sub>s</sub> has the energy scale comparable to the M ott gap. For the

lling control transition, it m ay have an energy scale as large as several eV as in the case of the cuprates (2 eV), while for the bandwidth-control transition, this energy scale is not necessarily large. The large energy scale of these M ott uctuations explains m any puzzling properties of m etals near the M ott insulator as we will discuss below.

Since the dom inant uctuation occurs at small but nonzero wavenum bers, the conservation law as in the density conservation at Q = 0 does not exist and the dynam ical exponent stays at  $z_t = 4$  for the lling-control transition. For the bandwidth-control transition, the

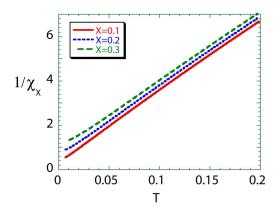


FIG. 5: Tem perature dependence of the inverse of the density susceptibility peak. A Curie-W eiss" tem perature dependence is observed in an extended region for several choices of doping X = 0.1;0.2 and 0.3. This linear tem perature dependence causes non-Ferm i-liquid properties.

real divergence at q = 0 again does not involve the conservation law because the doublon density does not commute with the Ham iltonian and is not conserved. Therefore, the dynam ical exponent again stays at four and the form Eq.(52) is justimed. This is in contrast with the ferrom agnetic uctuation at Q = 0 for the spin uctuations, where i! in Eq. (52) is replaced with i! = with / q so that the dynam ical exponent increases by one<sup>5</sup>.

Now we formulate a mode coupling scheme for the electron-density and doublon-density uctuations originating from the Mott criticality around smallQ. The inverse of the static susceptibility is obtained from Eq.(42) as

$$(Q;0)^{1} = 2a_{0}(T T_{c}) + 6bh_{Q}i + 12c h_{q}^{2}i;$$
 (53)

where we introduced the average of the density uctuation as  $h_q^2 i$ . This is given from the uctuation dissipation theorem as

$$h_{q}^{2}i = \frac{1}{2} \int_{1}^{Z} d! \operatorname{coth}(!=2T) \operatorname{Im}(q;!):$$
 (54)

In the inverse of the bare susceptibility, the mass term is renormalized by the modecoupling term proportional to  $\Pr_{q}^{P}h_{q}^{2}i$  in Eq.(53). By renormalizing the zero temperature value,  $T_{c}$  is renormalized to

$$T_{c}^{0} = T_{c} - \frac{6c^{X}}{a_{0}} h_{q}^{2} i(T = 0);$$
 (55)

where

$$h_{q}^{2}i(T = 0) = \frac{1}{2} \int_{0}^{Z_{1}} d! Im (q; !)$$
 (56)

is the zero-tem perature uctuation. Then the renorm alized inverse susceptibility is given by

$$(Q;0)^{1} = 2a_{0} (T T_{c}^{0}) + 6bh_{Q}i + 12c h_{q}^{2}i$$
(57)

with the de nition for the nite-tem perature correction;

$$h_{q}^{2}i = \frac{2}{0} \frac{2}{0} \frac{1}{1} \frac{1}{\exp(!=T) - 1} \operatorname{Im} (q; !):$$
(58)

We can solve Eqs.(52), (57) and (58) selfconsistently, where we take into account the G aussian uctuations of the density through the mode coupling. In the mode-coupling scheme, the critical exponents stay at the mean-eld values, which is justiled from the above arguments in Sec. IIII. However, elects of the uctuations are taken into account in a selfconsistent fashion. A similar phenomenological theory has been form ulated by Moriya for spin uctuations<sup>55</sup>.

## B. Perturbative self-energy

In the follow ing, we employ a perturbative treatment to understand the non-Ferm i-liquid behavior as well as superconducting instability. The perturbative scheme has a limited applicability for these highly nonperturbative phenomena of the density uctuations. How – ever, when the M ott criticality is properly taken into account through the phenomenological treatment of the density uctuations, we expect that the essence can be captured even when we employ a perturbation theory for the other part of calculations.

In the actual calculations for the realistic choice of parameters, a reasonable set of parameters can be derived in the following: We choose the parameter values of a lling-control transition for a two-dimensional system appropriate for the copper oxide superconductors inferred from the frequency dependence of the optical conductivity<sup>56,57</sup>, characteristic size of the observed inhom ogeneity<sup>48,49</sup> and the doping dependence of the density susceptibility in numerical<sup>22</sup> and experimental results, which suggest  $a_0 = 0$ ; b = 0.7; c = 100; c = 100;

the dielectric function (q = 0; !) obtained from the optical conductivity provides us with Im (q = 0; !) = Im [l = (q = 0; !)] 1. The obtained results for Im deduced from the experimental data for the optical conductivity have a prominent peak structure around 0.5–1 eV<sup>57</sup>, which indicates the characteristic energy scale of the density uctuations. A fler considering the screening e ect by the long-range C oulom b part, this suggests  $D_s$  has the order of 1eV. The uncertainty of the parameters remains because of the lack of accurate experimental probes to estimate the frequency and wavenum ber dependences of dynamical density uctuations. B asially, all the results presented here do not depend on Q within the choice 0 < Q < 0.2.

A san example, we consider the carrier doping in the H ubbard m odel with the dispersion of the square lattice E (q) =  $2t(\cos q_x + \cos q_y)$  with additional input of the density uctuations given by Eq.(52). Through the m ode coupling, the solution of the selfconsistent equations (52),(57) and (58) shows that the Curie-W eiss type behavior  $(T + )^1$  holds in an extended tem perature region with small W eiss tem perature near the m arginal quantum critical point. Figure 5 shows calculated results of such Curie-W eiss bahaviors in an extended tem perature region. The criticality stays at the m ean- eld form, while the Curie-W eiss form is retained over very large tem perature region with renormalized values of coe cients. Even when  $a_0 = 0$  is employed, we obtain the linear tem perature dependence of  $^1$ , namely the Curie-W eiss form in a wide tem perature region because of the linear tem perature dependence of  $h_q^2$ i.

Now we calculate the electron self-energy. The electron self-energy in the perturbation expansion up to the second order of the interaction for the lling control is given as

$$(q;!_{n}) = \frac{TU^{2} X}{2N} G(k;i!_{n}) X(q k;i(!_{n} !_{m})):$$
(59)

Here the in aginary part of the self-energy Im is governed by the Curie-W eiss behavior of  $_{\rm X}$  through Eq.(59). Because of the linear temperature dependence in  $^{-1}$  in an extended temperature region, we obtain the linear temperature dependence also for Im in a wide temperature region. In the marginal-critical region with  $_{\rm X}$  / X  $^{-1}$ , the standard Ferm i-liquid behavior Im / T<sup>2</sup> is replaced with the non-Ferm i-liquid form Im / T, which may cause various unusual properties. The resistivity in two-dimensional systems becomes nearly proportional to T as / Im / T in contrast to the standard Ferm i-liquid scaling

 $/ \text{Im} / \text{T}^2$ .

A long-standing puzzle in the doped M ott insulators is widely observed long-tailstructures in the optical conductivity extending up to the order of 1 eV in various transition m etal oxides and organic conductors<sup>1,56,57,58</sup>. The tail has a structure of power law decay in the optical conductivity as (!) ! <sup>p</sup> with p ranging between 0.3 and 1. O rigin of such long tail structure has to be attributed to uctuations in the energy scale of 1 eV and cannot be accounted for by the spin and orbital uctuations, since they have much lower energy scale typically less than 0.1 eV. W e note that the density uctuation m echanism exam ined in this article naturally accounts for such uctuations at large energy scale.

## V. SUPERCONDUCTIVITY EMERGING FROM MOTT CRITICALITY

A. Pairing originating from the marginal quantum M ott criticality

It is widely recognized that the origin of the high-tem perature superconductivity in the copper oxides<sup>6</sup> has to be explained by considering the strong electron correlation e ects, although the mechanism is still puzzling and not de nitely gured out. A fter the discovery, various aspects of magnetic mechanism swere extensively examined. From the weak coupling picture<sup>59,60</sup>, the spin uctuation theories were considered, where strong antiferrom agnetic uctuations were assumed to mediate the Cooper pairing. Then the origin of the high- $T_c$  superconductivity was assumed to arise from the criticality of the antiferrom agnetic quantum critical point. In the strong-coupling expansion represented by the t-J model<sup>61</sup>, it was claimed that the pairing is basically through the singlet form ation stabilized by the superexchange term proportional to J in the t-J model. In both of the approaches, the mechanism of the Cooper pairing is more or less the same and they are categorized as the magnetic mechanism.

On the other hand, from the initial stage of the studies on the cuprate superconductors, it has been well recognized that the superconductivity occurs in the region of the doped M ott insulator near the M ott transition<sup>62</sup>. However, since the criticality of the M ott transition was not well identified until recently, the role of the M ott criticality for the mechanism of the superconductivity was not well appreciated. In fact, as we already clarified in the previous sections, the M ott transition itself is a transition driven by the order parameter of the electron (or doublon-holon) density, and has nothing to do with the magnetic degrees

of freedom by itself. A lthough the antiferrom agnetic uctuations occur at (; ) in the magnetic B rillouin zone for the square lattice, the M ott criticality occurs independently through quite a di erent uctuation, namely through the singular density uctuations at sm all wavenum ber. If the antiferrom agnetic order exists at low temperature of the M ott insulating phase, the antiferrom agnetic uctuations around (; ) coexist with the density uctuations around sm all wavenum ber arising from the M ott criticality. It should also be

noted that this uctuation has a completely di erent origin from the ordinary charge-order uctuations at a commensurate wave vector, although the present instability may also trigger the charge ordering.

It is naturally expected that the density uctuations at small wavenum ber inherent to the M ott transition m ay play a novel role in stabilizing the superconducting phase. In fact, the density uctuations m ay be the origin of instabilities to various symmetry breakings including not only superconductivity but also charge and m agnetic orderings, since the diverging density uctuations are directly connected with the attening of the quasiparticle dispersions at the Ferm i level leading to the enhanced density of states. The diverging density of states widely enhances the instability for various orders.

The pairing mechanism arising from this density uctuation was recently studied by a perturbative scheme of the mode-coupling theory<sup>25</sup>. We here discuss superconductivity assuming the proximity to the Mott quantum critical point in detail. In the present scope, the density uctuations have the largest energy scale over spin and orbital uctuations and are the primary origin of the unusual properties. This proximity of the Mott transition indeed mediates the Cooper pairing through the enhanced density uctuations. When we follow the perturbative scheme, the elective interaction between two electrons is obtained from the density uctuations as

$$(q;i!_n) = U \quad U^2_X (q;i!_n) = 2$$
 (60)

up to the second order in U with <sub>x</sub> obtained from (52). Of course other uctuations as spin uctuations also a ect the e ective interaction. However, to extract the role of density uctuations clearly, we ignore the contribution from spin uctuations in this article as the rst step. In fact, the density uctuation plays the dom inant role because of its large energy scale. When spin uctuations are also considered, we expect that it reinforces the pairing, since both of the uctuations enhance the same type of pairing symmetry while they do not

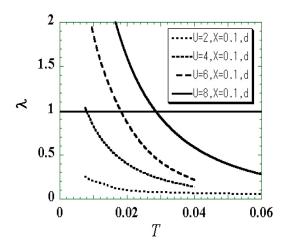


FIG. 6: Eigenvalues for the linearized E liashberg equation (61) are plotted as functions of tem perature. Since the eigenvalue for the  $d_{x^2 y^2}$  sym m etry is the largest, it is plotted for X = 0.1. The transition tem perature  $T_{sc}$  is obtained from the tem perature where the eigenvalue crosses = 1 (horizontal line). We have used the density susceptibility in Fig. 5. We plot for several choices of the Hubbard U interactions with the energy unit of the nearest-neighbor transfert on the square lattice Hubbard m odel.

interfere each other because of their uctuations at very dierent wave numbers as we see below. We obtain the linearized E liashberg equation for the superconducting gap as

$$(q;!_{n}) = \frac{T}{N} \sum_{k,m}^{X} G(k;i!_{m})G(k;i!_{m})$$

$$(q k;i(!_{n} !_{m})) (k;i!_{m});$$
(61)

where N is the number of sites. This E liashbrg equation is solved selfconsistently. Considering the level of perturbative approximations here, the rst nontrivial way to solve this problem is to take the bare G reen's function for G, and we ignore the normal self-energy corrections to G. In the calculation of G reen's function in Eq.(61), the standard Hubbard model on the square lattice is employed as an example. However, the nonperturbative e ect is taken into account through Eq.(52) for  $_{\rm X}$  with the parameter values introduced above. Then Eq.(60) is inserted to Eq.(61) and the eigenvalue is calculated for the right-hand side of Eq.(61). Namely, the linearized E liashberg equation is solved selfconsistently for the relevant parameter values for the cuprate superconductors as cited above.

#### B. Unconventional pairing

of approxim ations.

The solution of the E liashberg equation Eq.(61) for the parameter values above shows that the right hand side of the linearized E liashberg equation has the largest eigenvalue for the  $d_{x^2 \ y^2}$  pairing symmetry, which leads to the highest superconducting transition tem perature  $T_{sc}$  for this pairing symmetry as we show in Fig. 6. Figure 7 shows that the  $d_{x^2\ y^{\,2}}$  pairing sym m etry indeed w insover the eigenvalues for the other sym m etries including the sym m etry of the extended s-wave-symmetry pairing. It is remarkable that even though the uctuations are at a small wavenum ber Q, it generates the anisotropic pairing. This is because the e ective interaction is repulsive in them ost part of the B rilbuin zone because of the rst term in Eq. (60), while it becomes attractive only in the smallwavenum ber region. This forces the pairing to have an anisotropy with nodes. The  $d_{x^2 v^2}$  symmetry and its node position are understood because the largest gap grows in the (;0) and (0; ) regions, which is stabilized by the at dispersion. Then the only possibility is to make nodes in the diagonal direction in the Brillouin zone. We note that the gap am plitude may be substantially underestim ated because we have underestim ated the atness of the dispersion in G reen's function by taking the bare G reen's function instead of the correct one. Figure 6 shows how the eigenvalue grows with lowering tem peratures. The superconducting transition tem perature within this approximation is estimated from the temperature where the eigenvalue exceeds unity in Fig. 6. The transition temperature has the order of 0.01t to 0.05t as we see in Fig. 8, which corresponds to the order of 100K for the copper oxides when we take t 0:4eV.It should be noted that the large energy scale (namely the M ott gap scale 2 eV) of the density uctuation represented here by the parameter value  $D_s = 30X$  is crucial for achieving such a high transition tem perature. In other words, the high-energy excitations substantially contribute to enhancing the transition tem perature. It is rem arkable that within this sim ple approximation, the quantum M ott criticality has a dramatic e ect on the superconductivity, which is comparable or even larger than that by the magnetic mechanism in the same level

If we properly consider the self-energy e ects in Eq.(61), we expect that the superconducting transition temperature  $T_{sc}$  becomes vanishing at the M ott transition point although the pairing interaction is most enhanced at the M ott transition point because of the critical enhancement of the density uctuations. These two should cause the separation of  $T_{sc}$  and

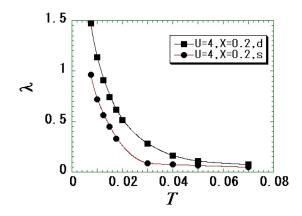


FIG. 7: Tem perature dependence of the eigenvalue for the linearized E liashberg equation for the  $d_{x^2 y^2}$  (squares) and extended s-wave (circles) symmetries.

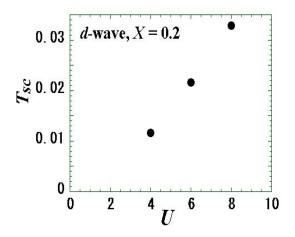


FIG.8: U dependence of the superconducting transition temperature for the  $d_{x^2 y^2}$  symmetry in the energy scale of t. The transfer is assumed to have t 0:4 eV and for other parameter values see the text.

the gap am plitude. It leads to the pseudogap behavior in the underdoped region. This is left for future studies. We note that one has to be careful in taking account of the self-energy e ects because a part of it appears through the density uctuation itself, which is already taken into account here but is beyond the presently available perturbative treatment in the literature. The present analyses based on the perturbative treatment and mean-eld-type E liashberg equation do not take into account uctuation e ects particularly in two-dimensional systems. In fact, in purely two-dimensional systems, we expect B erezinskii-K osterlitz-T houless (BKT) type transition for the gauge symmetry breaking of the superconductivity and this aspect is not considered here. Nonetheless, the present analyses have signing cance in the following points: First, even when the BKT transition is expected in pure two-dimensional system, its transition temperature has a comparable value to the mean-eld results as known in the analyses of the XY model universality. Therefore, the present mechanism of the superconducting transition may also work for the BKT transition at the similar temperature scale, which can be inferred from the present simple approximations. Second, the signing cance of the present approach is that the superconducting mechanism arises from a completely new origin of the proximity from the quantum M ott criticality with the enhanced density

uctuations at small wavenum ber. As a st step, clari cation of possible relevance in the experimental situation is desired even at the mean-eld level. Third, it is useful to compare consequences of the present mechanism with the conventional ones including magnetic

uctuation mechanisms at the same level of approximations. For the mean-eld analyses, it is possible because we have many available results for the conventional mechanisms in the literature. Fourth, in the cuprates, very weak interlayer coupling, which still does not destroy the dominance of two-dimensional M ott criticality in a wide region, may sensitively induce real superconducting transition as the three-dimensional one. This circum stance may show that the mean-eld treatment for the superconducting transition or ers a qualitatively correct way of understanding if the pairing mechanism is correctly picked up. M ore detailed analyses with consideration of the inherent two-dimensional uctuations and the resultant BKT transition is left for future studies.

The present pairing mechanism may also work near the bandwidth-control transition point. In fact the basic mechanism can be straightforwardly applied to the region near the critical end point of the bandwidth-control transition. This may explain the superconducting phase observed near the M ott transition point of -ET compounds fam ily<sup>63</sup>.

The superconductivity near the valence instability point was studied theoretically as a model for  $C \in Cu_2Si_2$ ,  $C \in Cu_2Ge_2$ , and other heavy ferm ion compounds<sup>64,65</sup>. Since we expect a similar novel criticality to the present M ott criticality, it would be an intriguing issue to pursue the mechanism of the superconductivity along the same line.

Since electron density uctuations of course strongly couple with phonon modes, the phonons also supplement this density uctuation mechanism. In fact, the strong coupling to small wavenum ber phonon necessarily occurs, if the enhanced electron density uctuations already exist in the M ott critical region. This may reinforce the strong coupling to phonons even when the conventional electron-phonon coupling is rather weak. In fact, the  $B_{1g}$  out-of-plane phonon mode with a small momentum transfer<sup>66</sup> may have a relevance and presumable resultant kink structure in the angle-resolved photoem ission spectra should be considered under this circum stance.

## VI. SUMMARY AND DISCUSSION

In this paper, it has been shown that the M ott transition is successfully described by a new fram ework for quantum phase transitions. The natural order parameter for the M ott transition is the electron doping concentration for the lling-control transition. For the bandw idth-control transition, the natural order parameter is the doublon (or holon) density. At zero tem perature, the phase boundaries of m etals and M ott insulators always exist as the M ott transition, which occurs either as the rst-order or continuous transitions.

If the M ott transition occurs as the continuous transition at zero temperature and other spontaneous symmetry breakings are not involved, the metals and insulators are adiabatically connected at nite temperatures. We call this regime the quantum regime surrounding the  $T_c = 0$  boundary. On the other hand, if the transition occurs as the rst-order transition at T = 0 and term inates as the critical point above the Ferm i degeneracy temperature, we call it the classical regime. Sandwiched by these two regimes, the marginal quantum critical region appears, where the rst-order boundary and the continuous  $T_c = 0$  boundary meet at T = 0.

A lihough the density uctuation is completely suppressed in the M ott insulator because of the M ott gap, the criticality of the continuous M ott transition in the m etallic side can be described by the critical enhancement of the density uctuation at smallwavenum bers in contrast to the naive expectation. This critical enhancement indeed occurs at nite-temperature M ott critical line as well as at the marginal quantum critical point. The marginal quantum criticality shows nontrivial and novel features.

In the classical regime around the high critical tem perature, the M ott criticality is de-

scribed by the Ising universality class. However, in the quantum regime, the clari ed Mott criticality indicates the breakdown of the Ginzburg-Landau-Wilson (GLW) scheme. The quantum dynamics is derived from the path-integral form alism with the one-to-one correspondence between single-particle dynam ics and two-particle correlations. The divergence of time scale at the transition is described by the dynam ical exponent z = 2 for the quantum region and z = 4 for the marginally quantum region. Remarkably, it is shown that the free energy has nonanalytic expansion with respect to the order parameter, with power depending on spatial dimensionality d for the quantum as well as the marginally quantum criticality, in marked contrast with the GLW expansion, which is demensionality independent. This unusual expansion results in dimensionality-dependent critical exponents, which also indicates that the M ott transition occurs always at the upper critical dim ension at any d. Then, at any d, the scaling relations and the hyperscaling are still satis ed while the mean-eld description is basically justi ed for the critical exponents except for the possible logarithm ic corrections. They are totally described by a new universality class. Particularly when the M ott critical tem perature becom es lowered just to zero tem perature, the m arginal quantum critical point appears and the critical exponents are given by = 2 d=2; = d=2and = 4=d.

The present theoretical fram ework for the quantum M ott criticality has clari ed m any aspects which are consistent with the experim ental results near the M ott insulator. These are sum m arized in the following:

First, the universality class of the quantum M ott transition well explains the otherwise puzzling critical exponents recently discovered in  $-(ET)_2 Cu N (CN)_2 |C|$ ; = 1; = 1 and = 2. This exponents are identified as those at the marginal quantum critical point in two-dimensional systems. The scaling description is completely consistent with both the classical Ising-type transition observed in  $V_2O_3$  and the quantum transition observed in

-(ET)<sub>2</sub>Cu[N(CN)<sub>2</sub>]Claswellasin -(ET)<sub>2</sub>Cu<sub>2</sub>(CN)<sub>3</sub>.

Second, such unusual exponents and the new universality class at the marginal quantum critical point inevitably cause the di erentiation of electrons in the momentum space even when the large Ferm i surface with the contained Luttinger volume is expected. This draws a concrete picture how the Ferm i liquid breaks down to the Mott insulator. The di erentiation along the Ferm i surface is the driving mechanism of the emergence of the at dispersion, and the arc structure observed by the angle resolved photoem ission experiments

in the cuprate superconductors. The di erentiation generates particular points on the Ferm i surface responsible for the criticality, which is the reason why the hyperscaling relation is satis ed in the present theory.

Third, approaching the marginal quantum critical point, the system becomes more and more sensitive to the external perturbations and is easily driven to the inhomogeneous state, which has been suggested in various types of surface probes. We have estimated the typical length scale of the inhomogeneity determined from the balance of the Mott criticality and the long-range C oulom b interaction in the lling-control transition.

At the same time, the universality class of the M ott criticality at nite tem peratures in the classical region is protected from the random ness because the Ising universality at nite tem peratures is not in uenced by the small random ness. The rst-order transition is only driven by the mechanism of the Mott transition equivalent to the Ising class. The universality class of the critical point at the term ination point of the st-order transition m ay receive fewere ects of Anderson localization, because the Anderson transition does not drive the st-order transition at all. The insensitivity to the random ness is particularly true in three dimensions. In purely two dimensional systems, however, the situation is nontrivial because of the sensitive random eld e ects on the Ising transition, which will be discussed in a separate paper. This is also the origin of the tendency for the spatial inhom ogeneity. At the marginal quantum critical point, we also expect that the universality is protected against random ness at least in three dimensions because of diverging density of states at the gap edge and e cient screening through divergent density susceptibility. Near the marginal quantum critical point, the enhanced density of states in plies that the Thom as Ferm iscreening length becomes short, which leads to a more e cient screening of the random potential by the fewer carriers. Then contrary to the naive expectation, the density uctuation at a long length scale appears. A long the  $T_c = 0$  boundary, the metallic phase may be under a severe e ects of random ness and the continuous m etal-insulator transition is eventually triggered by the Anderson localization.

The lling-control transition requires a special care because of the long-range C oulom b interaction. For charged electrons, the real divergence of the density uctuation at strictly q = 0 is suppressed. However, the density uctuations are still strongly enhanced at a sm all nonzero wavenum ber, which m ay cause unusual properties. In addition, if dispersive light carriers coexist with the carriers near the M ott insulator, the screening and compensation

by such dispersive and good metallic carriers allows the critical divergence of the density

uctuation for the correlated carriers. This appears to be realized indeed in the cuprate superconductors.

The fourth point for the experimental relevance of the marginal quantum criticality is the non-Ferm i-liquid properties. The non-Ferm i-liquid properties observed in the doped M ott insulators with two-dimensional anisotropy are accounted for by the density uctuations arising from the quantum M ott criticality. This in fact explains the T-linear resistivity in two dimensions, when we employ the mode coupling theory. In particular, the uctuations at the energy scale as large as 1 eV observed as the long tail in the optical conductivity universal in transition m etal compounds and organic compounds are explained not by spin or orbital uctuations but by this density uctuation of the quantum M ott criticality.

We have also shown that the mechanism of the high-T<sub>c</sub> superconductivity can be ascribed to the density uctuations originating from the marginal quantum M ott criticality. A blough the density uctuation occurs at small wave number, it causes the unconventional pairing with a nodal structure. For the realistic parameter values of the cuprate superconductors, the solution of the linearized E liashberg equation has the highest transition temperature of the order of 100K for the  $d_{x^2 \ y^2}$  wave symmetry. It is remarkable that, within the present level of approximation, the density uctuations inherent near the quantum M ott criticality overlooked in the literature cause comparable or even larger elects than the spin uctuation mechanisms extensively studied for the cuprate superconductors. The large energy scale of the density (charge) uctuations may help even stronger instability towards the superconductivity, if this instability could be more carefully tuned by the design of

From the experimental point of view, it is highly desired to develop a good experimental probe for studying the dynamical and short-range density (charge) correlations. In contrast to the magnetic correlations well studied by neutron scattering and NMR, experimental probes for the wavenumber and frequency dependent charge correlations of electrons are poor. We can study the optical conductivity and dielectric functions only at zero wavenum – ber while STM and several microscopes can detect only the static structure on the surface. Ram an scattering is not powerful enough so far for the study of the system atic wavenum ber dependence. Electron energy loss spectra and inelastic X-ray scattering in principle probe the dynam ical density correlations while the present energy resolution is rather poor. To

m aterial param eters. This is a challenging future task.

uncover the whole feature of physics near the M ott transition, it would be highly desired to develop experimental probes for the frequency and momentum dependence of electron density correlations and it will make a breakthrough in this eld. Our prediction from the present work is that the extended charge (density) uctuations at small wavenum bers may be observed in the frequency and wavenum ber dependent spectra in the critical region of a certain class of the M ott transitions in transition m etal com pounds and organic conductors. The density uctuation may also occur with a compensation between two dimensity and the strongly correlated carriers near the M ott insulator. This compensated density uctuation will require a more re-ned probe to be detected. This will reveal the missing ring of various puzzling properties including the mechanism of the high-T<sub>c</sub> cuprate superconductors and the criticality of the M ott transition in the organic conductors.

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